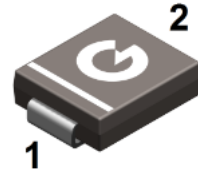


Features

- For surface mounted applications
- Ideal for automated placement
- Low forward voltage drop
- High forward surge current capability
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF

Cathode Anode
1 2



SMC

Mechanical Data

- Case: SMC
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TS3D	SMC	3000 pcs / Tape & Reel	S3D
TS3G	SMC	3000 pcs / Tape & Reel	S3G
TS3J	SMC	3000 pcs / Tape & Reel	S3J
TS3K	SMC	3000 pcs / Tape & Reel	S3K
TS3M	SMC	3000 pcs / Tape & Reel	S3M

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	TS3D	TS3G	TS3J	TS3K	TS3M	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	140	280	420	560	700	V
DC Blocking Voltage	V _{DC}	200	400	600	800	1000	V
Average Forward Output Current	I _{F(AV)}	3.0					A
Peak Forward Surge Current, 8.3ms Single Half Sine wave	I _{FSM}	100					A

Thermal Characteristics

Parameter	Symbol	TS3D	TS3G	TS3J	TS3K	TS3M	Unit
Thermal Resistance Junction-to-Air *1	R _{θJA}	59					°C/W
Thermal Resistance Junction-to-Case *1	R _{θJC}	16					°C/W
Thermal Resistance Junction-to-Lead *1	R _{θJL}	13					°C/W
Operating Junction Temperature Range	T _J	-55 ~ +150					°C
Storage Temperature Range	T _{STG}	-55 ~ +150					°C

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	$V_{(BR)}$	$I_R = 2\mu\text{A}$, TS3D	200	-	-	V
		$I_R = 2\mu\text{A}$, TS3G	400	-	-	V
		$I_R = 2\mu\text{A}$, TS3J	600	-	-	V
		$I_R = 2\mu\text{A}$, TS3K	800	-	-	V
		$I_R = 2\mu\text{A}$, TS3M	1000	-	-	V
Forward Voltage *2	V_F	$I_F = 3.0\text{A}$	-	-	1.15	V
Maximum Peak Reverse Current *3	I_R	Rated V_R , $T_J = 25^\circ\text{C}$	-	-	10	μA
		Rated V_R , $T_J = 125^\circ\text{C}$	-	-	125	μA
Diode capacitance	C_J	$V_R = 4\text{V}$, $f = 1\text{MHz}$	-	36	-	pF

Notes:

1. The data tested by surface mounted on p.c.b. with 10 mm x 20 mm x 0.1 mm copper pad area
2. The data tested by pulsed, pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 1\%$
3. The data tested by pulsed, pulse width $\leq 40\text{ms}$

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

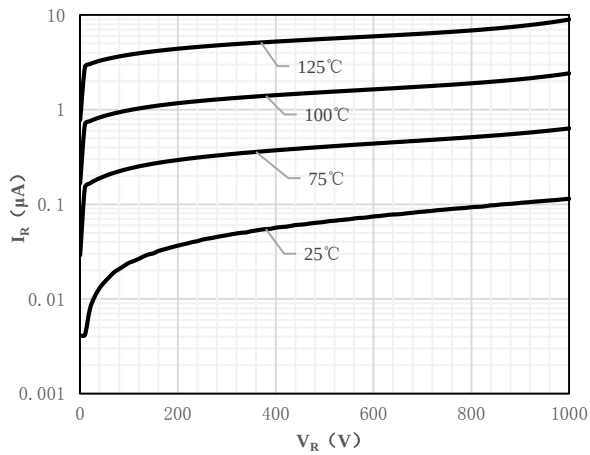


Fig 1 Typical Reverse Characteristic

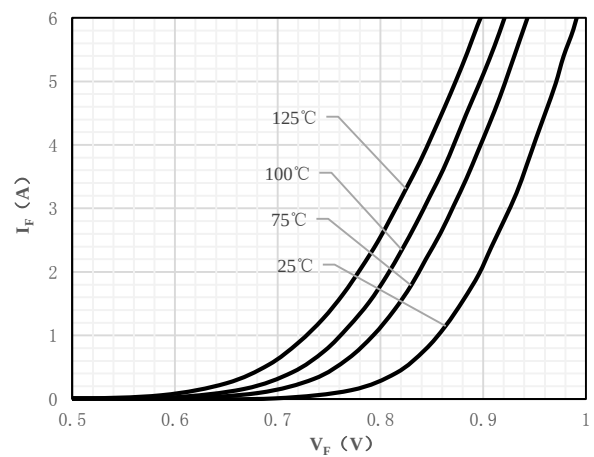


Fig 2 Typical Forward Characteristics

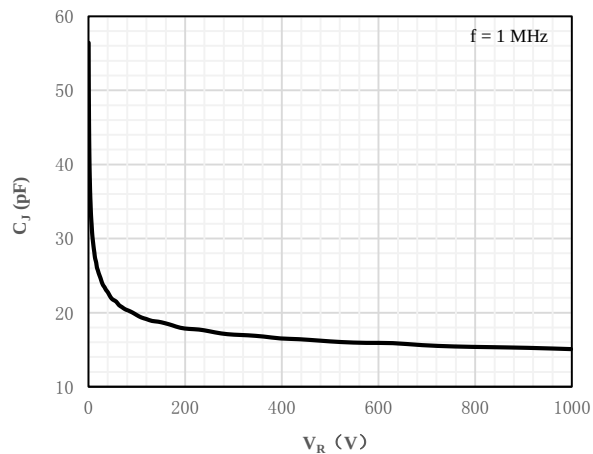


Fig 3 Capacitance vs. Reverse Voltage

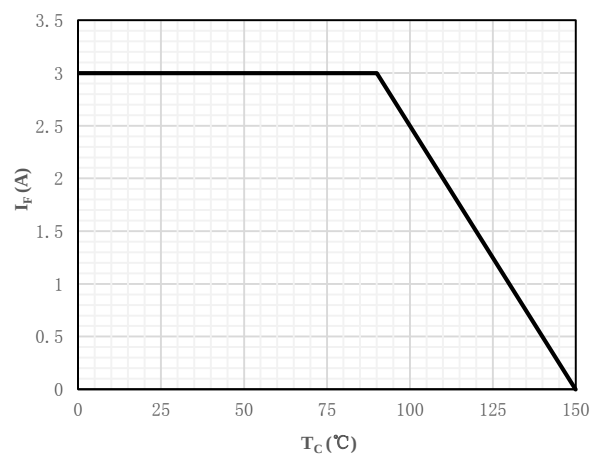


Fig 4 Forward Current Derating Curve

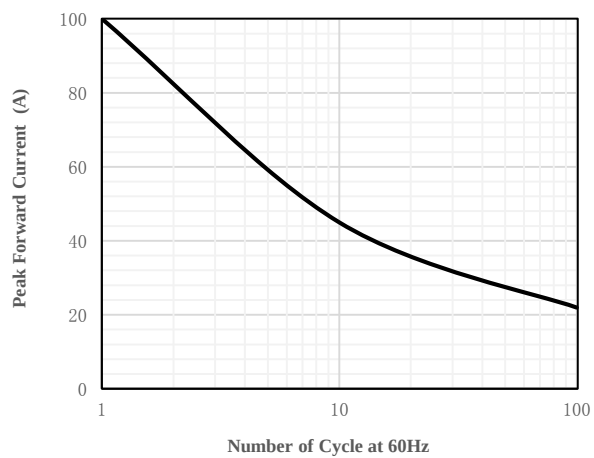
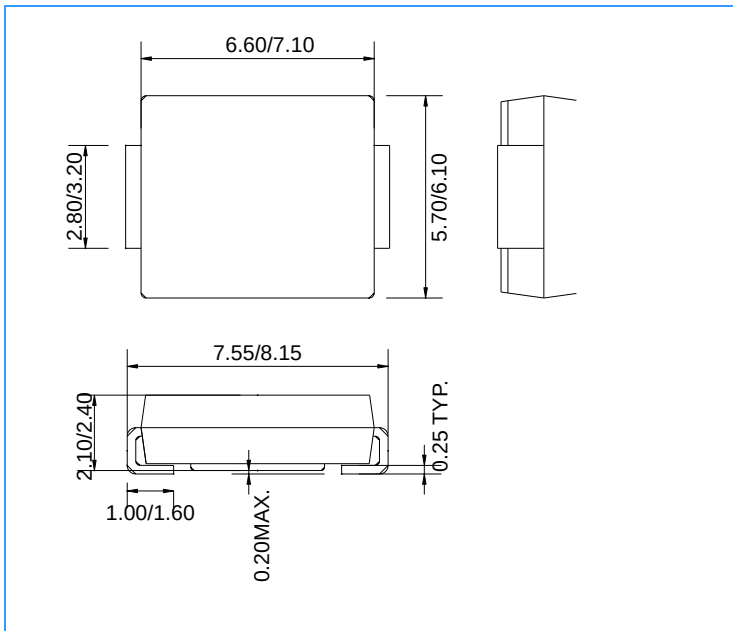


Fig 5 Surge Current Derating Curve

Package Outline Dimensions (Unit: mm)



Mounting Pad Layout (Unit: mm)

